

ON Semiconductor®

FDMS9410-F085

N-Channel PowerTrench[®] MOSFET

40 V, 50 A, 4.4 mΩ

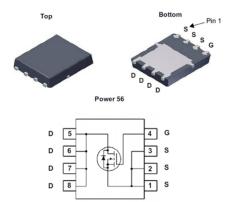
Features

- Typical $R_{DS(on)}$ = 3.7 m Ω at V_{GS} = 10V, I_D = 50 A
- Typical Q_{q(tot)} = 24 nC at V_{GS} = 10V, I_D = 50 A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

Applications

- Automotive Engine Control
- PowerTrain Management
- Solenoid and Motor Drivers
- Electronic Steering
- Integrated Starter/Alternator
- Distributed Power Architectures and VRM
- Primary Switch for 12V Systems





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For current package drawing, please refer to the web-site at https://www.onsemi.com

MOSFET Maximum Ratings T_J = 25°C unless otherwise noted.

Symbol	Parameter	Ratings	Units	
V _{DSS}	Drain-to-Source Voltage		40	V
V _{GS}	Gate-to-Source Voltage		±20	V
I _D	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	50	^
	Pulsed Drain Current	T _C = 25°C	See Figure 4	Α
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	39	mJ
P _D	Power Dissipation		75	W
	Derate Above 25°C		0.5	W/ºC
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case		2	°C/W
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	50	°C/W

Notes:

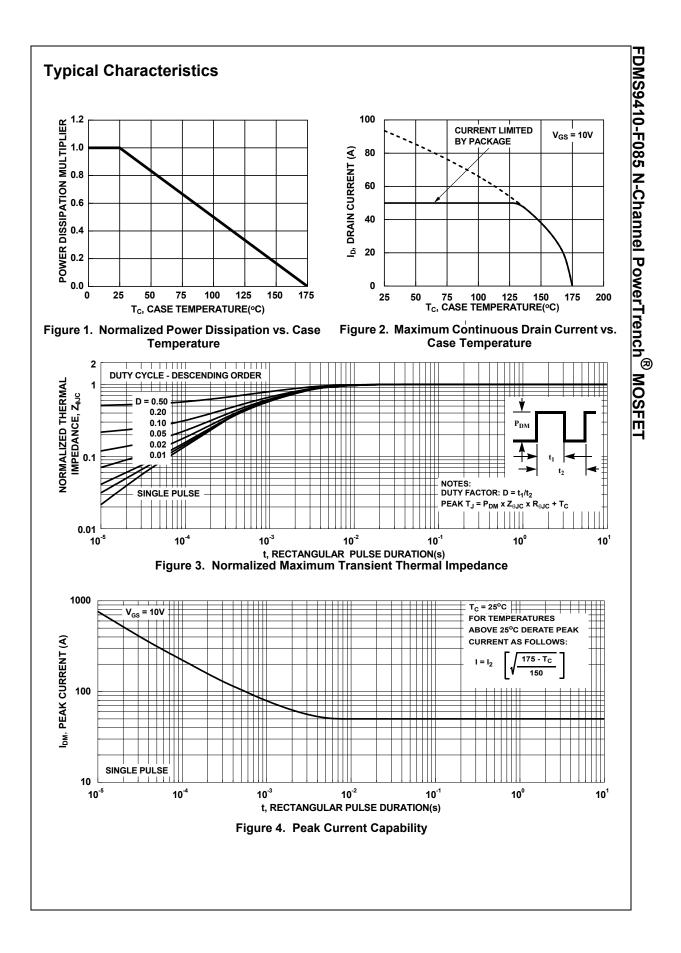
- 1: Current is limited by bondwire configuration.
- 2: Starting T_J = 25°C, L = 0.1mH, I_{AS} = 28A, V_{DD} = 40V during inductor charging and V_{DD} = 0V during time in avalanche. 3: $R_{0,JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design, while $R_{\theta JA}$ is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

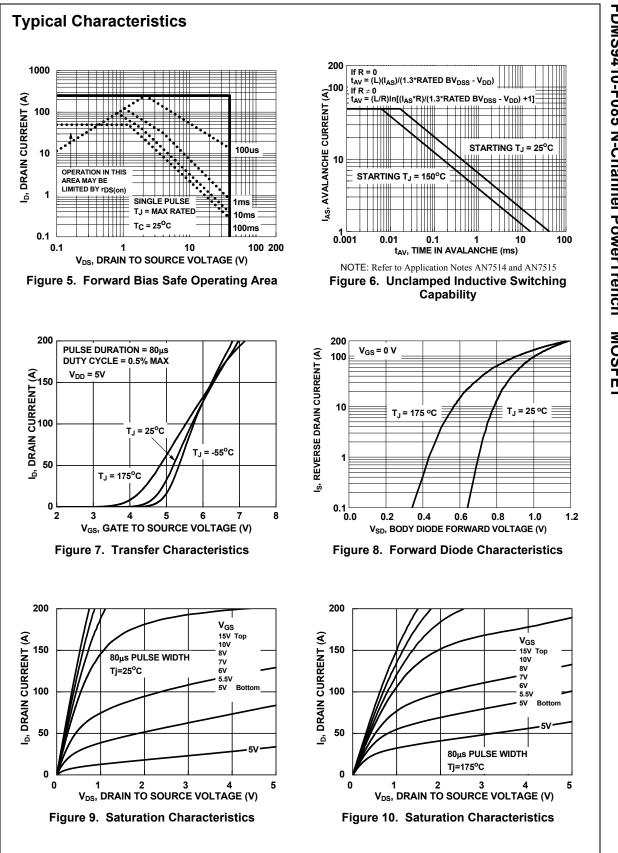
Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMS9410	FDMS9410-F085	Power56	13"	12mm	3000units

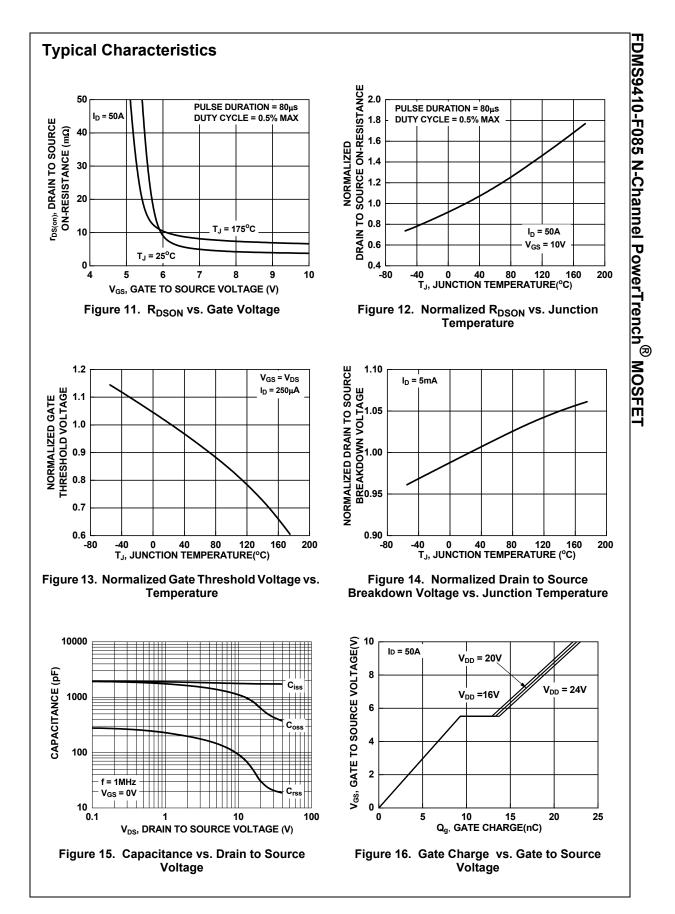
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Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
Off Cha	racteristics						
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V		40	-	-	V
		V _{DS} =40V, 1		-	-	1	μA
I _{DSS}	Drain-to-Source Leakage Current	V _{GS} = 0V 1	$\Gamma_{\rm J} = 175^{\rm o} {\rm C} \ ({\rm Note} \ 4)$	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA
On Cha	racteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250μA		2.0	3.2	4.0	V
		I _D = 50A,	Т _. = 25 ⁰ С	-	3.7	4.4	mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 10V	T _J = 175 ^o C (Note 4)	-	6.6	7.9	mΩ
Dynami	ic Characteristics						
C _{iss}	Input Capacitance	— V _{DS} = 20V, V _{GS} = 0V, f = 1MHz		-	1790	-	pF
C _{oss}	Output Capacitance			-	620	-	pF
C _{rss}	Reverse Transfer Capacitance			-	32	-	pF
R _g	Gate Resistance	f = 1MHz		-	2.0	-	Ω
Q _{g(ToT)}	Total Gate Charge	$V_{GS} = 0 \text{ to } 10V$ $V_{DD} = 32V$ $V_{GS} = 0 \text{ to } 2V$ $I_D = 50A$		-	24	36	nC
Q _{g(th)}	Threshold Gate Charge			-	3.3	-	nC
Q _{gs}	Gate-to-Source Gate Charge			-	9.1	-	nC
Q _{gd}	Gate-to-Drain "Miller" Charge			-	4.5	-	nC
Switchi	ng Characteristics						
t _{on}	Turn-On Time			-	-	27	ns
t _{d(on)}	Turn-On Delay			-	12.1	-	ns
t _r	Rise Time	V _{DD} = 20V, I _D		-	5.9	-	ns
t _{d(off)}	Turn-Off Delay	V_{GS} = 10V, R_{GEN} = 6 Ω		-	18.8	-	ns
t _f	Fall Time			-	5.0	-	ns
t _{off}	Turn-Off Time			-	-	31	ns
Drain-S	ource Diode Characteristics						
V	Source to Drain Diade Voltage	I _{SD} =50A, V _{GS} = 0V		-	-	1.25	V
V _{SD}	Source-to-Drain Diode Voltage	I _{SD} = 25A, V _{GS} = 0V		-	-	1.2	V
1	Reverse-Recovery Time		_D /dt = 100A/µs	-	45.5	59	ns
t _{rr}		$V_{DD} = 32V$		-	33.2	43	nC





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